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RESEARCH ARTICLE



Highly crystalline hexagonal PbI₂ sheets on polyaniline/ antimony tin oxide surface as a novel and highly efficient photodetector in UV, Vis, and near IR regions

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Abstract

The work reports on the preparation of polyaniline/lead iodide optoelectronic photodetector on antimony tin oxide (ATO) glass (PANI/Pbl₂/ATO) for providing a low-cost light sensor in the UV, Vis, and near IR regions (wide optical range photodetector). The deposition of Pbl₂ nanoparticles was carried out on the surface of PANI using the ionic adsorption deposition method. Four ATO/PANI/Pbl2 composites (I, II, III, and IV) were produced by varying the Pb²⁺ concentrations (0.01, 0.03, 0.05, and 0.07 M, respectively). The chemical structure, morphology, optical, and electrical properties were assessed using different analytical tools. Scanning electron microscopy (SEM) imaging revealed the formation of a nanoporous PANI network. After Pbl₂ incorporation within the PANI network, white nanoparticles formed on the surface. The average size of the Pbl₂ nanoparticles was 220, 270, 280, and 320 nm for Pb²⁺ concentration of 0.01, 0.03, 0.05, and 0.07 M, respectively. Moreover, x-ray diffraction analysis confirmed PANI/Pbl2 composite formation, as witnessed by the appearance of new peaks at 12.77°, 34.31°, and 38.8 ° characteristic of Pbl₂. Through the optical analyses, the band gap values of the PANI/Pbl₂ composites I, II, III, and IV were 2.63, 2.51, 2.46, and 2.48 eV, respectively. ATO/composite III was applied as an optoelectronic device for detection the light under different intensities or wavelengths, in which the current density (J_{ph}) increase from 2.5 to 3.42 mA cm⁻² upon increasing of the light intensity from 25 to 100 mW.cm⁻², respectively. Moreover, the J_{ph} recorded an optimum value of 3.33 mA cm⁻² at 390 nm, which decreased to 2.09 mA cm⁻² at 490 nm and increased again to 3.13 mA cm⁻² at 636 nm. The optoelectronic photodetector exhibited an optimum incident photon to electron conversion efficiency (IPCE) of 10.7% at 390 nm. The photoresponsivity (R) and detectivity (D) were determined to be 107 mA cm^{-2} and 3.38 $\times\,10^{10}$ Jones,

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Deanship of Scientific Research at Jouf University, Grant/Award Number: DSR-2021-03-0321 respectively. Finally, a simple mechanism was proposed to account for the response of the prepared optoelectronic devices to the photon flux. Soon, our team will work on design an optoelectronic device that can be applied in the industrial field through the high technology device such as cameras and aircrafts for light detection.

KEYWORDS

ATO/PANI/Pbl2 composites, optical properties, photocatalytic activities

1 | INTRODUCTION

Optoelectronic photodetectors are very promising devices, owing to their applications in different fields such as streets lighting, smart windows, spacecraft, and cameras.^{1–3} These optoelectronic devices facilitate light detection under different intensities and wavelengths. The light detection takes place through the activation of the photodetector materials with a photon flux that causes electronic level splitting, followed by hot electrons collection over the photodetector surface. These electrons produce J_{ph} and represent the rate of the photoelectrochemical process.

Many materials such as metal oxides, sulfides, and nitrides have been studied for light detection in various light regions.^{1,4,5} The performance of photodetectors could be enhanced by increasing the density of active sites on their surface. One efficient route to achieve this goal is through the utilization of materials featuring high surface area. Therefore, nanomaterials such as nanorods, nanotubes, nanowires, and nanosheets have been widely investigated for light detection.^{6–8}

Wang et al⁹ fabricated a photodetector based on CuO nanowires for IR detection. The device exhibited low efficiency with a J_{ph} value of 20 μ A at a bias voltage of +5 V. Bai et al¹⁰ prepared ZnO/CuO nanocomposite photodetector and recorded a small J_{ph} value of 107 μ A at +1 V. Hang et al¹¹ studied the ability of Si heterojunction as a photodetector, the device achieved a J_{ph} value of 4.5 μ A at a bias voltage of 0 V. Moreover, Pbl₂ doped Ag 5% nanostructure film was prepared by pulsed laser deposition and was applied as photodetector, the J_{ph} value was 0.2 mA at a bias voltage of 6 V.¹² The Pbl₂/graphene composite nanoplates was applied as photodetector, the J_{ph} value was 0.4 μ A at a bias voltage of 2 V.¹³

Conductive polymers represent a promising category of polymers applied in the energy field. The response of these polymers to the light flux depends on the electron-hole separation. For example, poly-3-hexylthiophene was applied as a photodetector layer inside the eye.¹⁴ Other studies were carried out using iron-doped polymethylmethacrylate (Fe-doped PMMA)¹⁵ and PMMA/styrene/ carbon nanotubes composite¹⁴ as optoelectronic materials for the light detection.¹⁶ Polyvinylpyrrolidone/CsPbBr₃ composite was prepared and used as an optoelectronic device, the J_{ph} was 0.01 mA at 2 V.¹⁷ Moreover, various studies were carried out on aniline derivatives such as triphenylamine as optoelectronic device, reaching a J_{ph} of 0.001 mA at 0 V.¹⁸ The effect of fluorine-doped benzodithiophene was theoretically studied, revealing an

enhancement in the optical properties of the polymer for the optoelectronic applications.¹⁹ Moreover, Jha et al²⁰ has worked on recycling of nanofiber PANI-Pb nanocrystals waste for generating high-performance super-capacitor electrodes. Moreover, they were worked on nanofibers to nanocuboids of polyaniline self-assembled materials through which toxic heavy metal ions are automatically removed from aqueous solution.²¹

Although the previous literature revealed the benefits of the application of polymers as optoelectronic materials, there were many drawbacks related to the high-cost techniques for the preparation process, low optoelectronic efficiency, small *R* or *D* values, and low device reproducibility. Moreover, most of the previous literature focused on light detection in just a single region, UV, Vis, or near IR.

In our previous work, we synthesized TiO₂/TiN nanotubes using Al₂O₃ template; these tubes operated as a high efficient photodetector with IPCE, *R*, and *D* of 9.64%, 450 mA W⁻¹, and 8.0×10^{12} Jones, respectively.²² Moreover, we have studied the effect of Au on the TiO₂/TiN nanotubes' performance. The device achieved an efficiency of 10.25%, with *R* and *D* values of 438 mA W⁻¹ and 8.86 × 10¹² Jones, respectively.²³ In addition to that, the effect of alkali metal on CdS performance was studied. IPCE, *D*, and *R* values of >10%, 1.5 × 10¹⁰ Jones, and 38 mA W⁻¹ were recorded, respectively.²⁴

Our current study alleviates the previous limitations through the synthesis of a high efficiency optoelectronic photodetector ATO/ PANI/Pbl₂, in which the geometric hexagonal Pbl₂ is decorated inside PANI. This highly optical responding composite can detect the light in abroad light regions: UV, Vis, and IR. Moreover, the photodetector response to the light under different intensities from 25 to 100 mW cm⁻² with high IPCE, *R*, and *D* values that represent the high light sensing efficiency. In addition to that, the device displayed high reproducibility for light sensing. Through our study, the utilization of an in situ polymerization process to deposit a porous polyaniline (PANI) layer on antimony tin oxide (ATO) glass was carried out. The PANI matrix assisted further deposition of Pbl₂ nanosheets. The chemical structure, morphology, optical and electrical properties of the obtained materials were examined using different analytical tools. The influence of light intensity (25-100 mW cm⁻²) and wavelength (390-636 nm) on the device performance was studied. Finally, a plausible mechanism was proposed for the light sensing using the polymer composite optoelectronic device.

2 | EXPERIMENTAL SECTION

2.1 | Materials

 $Pb(NO_3)_2$ was purchased from El Naser chemical Co., Egypt. Aniline, iodine (I_2), and potassium iodide (KI) were bought from Biochem Company, Egypt. Silver paste, acetic acid (CH₃COOH), and ammonium persulfate ([NH₄]₂S₂O₈) were obtained from Alpha chemical Co., Egypt. ATO glass was purchased from American Elements, USA.

2.2 | Preparation of PANI/Pbl₂ on antimony tin oxide glass

Polyaniline (PANI) was prepared through an in situ oxidation polymerization method on ATO glass. A volume of 50 ml of aniline (0.1 M) was dissolved in 0.5 M CH₃COOH under ultrasonication (at room temperature for 30 min). Separately, 50 ml of 0.15 M (NH₄)₂S₂O₈ (oxidant) was nicely dispersed in 0.5 M CH₃COOH under ultrasonication. Then, the oxidant solution was added dropwise onto the aniline solution in the presence of an ATO glass. After 1 h, PANI precipitate was formed over the ATO glass. The ATO/PANI was dried at 60°C for 6 h and then dipped in Pb(NO₃)₂ solution (50 ml) at different concentrations (0.01-0.1 M) for 2 h at 298 K. The resulting ATO/PANI/Pb²⁺ film was dipped into 0.01 M I_2 aqueous solution (50 ml) for 15 min. During this process, Pbl₂ precipitates and coats of the PANI network. This reaction carried out at room temperature, this led to the arrangement of Pbl₂ on the PANI surface during the composite formation. The optimum ATO/PANI/Pbl2 composite was determined from the optimum light absorbance values through optical absorption analyses. By varying the Pb²⁺ concentration (0.01, 0.03, 0.05, and 0.07 M), ATO/ PANI/Pbl₂ composites I, II, III, and IV are prepared, respectively. The hexagonal Pbl₂ shape on the PANI surface increases the light absorption properties.

2.3 | Characterization

X-ray diffraction (XRD) patterns of the samples were recorded on a Bruker D8 advance diffractometer using Cu K α radiation ($\lambda = 0.15418$ nm). The morphology of the samples was studied by a field-emission scanning electron microscope (FE-SEM, Hitachi, S-4800) at an acceleration voltage of 5.0 kV. The optical analyses of the samples were carried out using a double beam spectrophotometer (Perkin Elmer Lamba 950, USA). Raman spectra were performed using Enwave Raman microscopy (spot 1 μ m) with a 532 nm laser excitation.

2.4 | Electrochemical measurements

All the electrochemical measurements were carried out using the electrochemical workstation (CHI660E) through the voltage range from -1 to +1 V, as shown in Figure 1. The electrochemical measurements

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were acquired under a Xenon lamp, in which ATO and ATO/PANI/ Pbl₂/Ag represent the two sides electrodes of the photodetector. The effect of light intensity (25–100 mW cm⁻²) and light wavelength (390–636 nm) on the prepared photodetector performance was assessed. Moreover, the reproducibility and dark current were evaluated. The measurements were carried out at 25°C in air environment.

3 | RESULTS AND DISCUSSION

3.1 | Structural, optical, and morphological properties

The XRD plots of the prepared PANI and PANI/PbI₂ composites (I, II, III, and IV) are shown in Figure 2A. The PANI peaks (black line) appeared at $2\theta = 20.78^{\circ}$ and 25.55° and are assigned respectively to the (021) and (200) diffraction planes. These semi-sharp peaks indicate the lamellar structure nature of the prepared PANI.²⁵

After PANI/Pbl₂ formation, there is an obvious shift in the PANI peak located at 25.55° -26.05°, and the peak intensity increases from composite I to III. The shifts in the peak is related to the composite formation, the increasing in the intensity indicate high crystallinity of the formed composite.^{26.27}

Moreover, after composite formation, there is an appearance of new peaks at 12.77°, 34.31°, and 38.8 ° characteristic of PbI_2 .²⁸ The crystal size of composite III was determined to be 33.3 nm (for the peak at 12.77°) using the Scherrer equation (Equation 1):

$$D = 0.94\lambda/\beta \cos\theta \tag{1}$$

ß denotes the full-width half maximum,²⁹ λ is the wavelength (0.154 nm), and θ corresponds to the Bragg's angle.

The Raman spectra of PANI and its Pbl₂ composites I, II, III, and IV are depicted in Figure 2B. From these results, one clearly sees some differences in the peaks related to the PANI and PANI/Pbl₂ composites, proving Pbl₂ incorporation in the PANI network. The Raman peaks at 1584 and 1489 cm⁻¹ are related to the C-C and N–H benzene ring vibrations, respectively.³⁰ The peaks at 1160 and 1220 cm⁻¹ are related to the C–H stretching vibrations.^{31,32} These peaks increase with increasing of the Pbl₂ concentration from composite I to III, then decrease in composite IV. Moreover, the peak at 400 cm⁻¹ in the PANI (black line) is related to the in-plane vibration modes. The peak at 180 cm^{-1} is characteristic of the A_1^2 hexagonal vibration mode of PbI₂,³³ Moreover, this peak confirms the crystallinity of the Pbl₂ material.³⁴ The effect of crystallinity of Pbl₂ appears clearly in the composite III that has the optimum intensities of the peaks in comparison with other composites. The results are in full accordance with the XRD analyses.

The optical absorption spectra of the PANI and PANI/Pbl₂ composites are displayed in Figure 2C. The PANI absorption peaks are located in the UV region at 325 nm and in the Vis region at 450 and 600 nm. After the formation of the PANI/Pbl₂ composites, the peak intensities at 325 and 600 nm increased, and new additional peak at

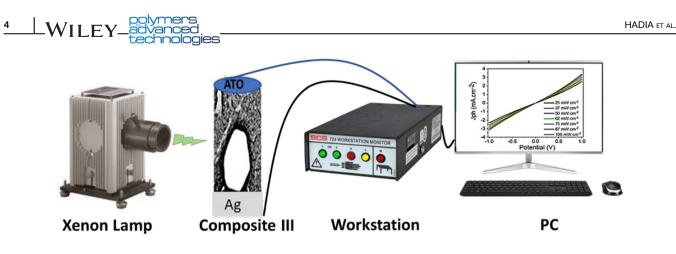


FIGURE 1 The schematic diagram of the ATO/PANI/Pbl₂ photodetector electrochemical measurements using the power station under xenon lamp irradiation. ATO, antimony tin oxide; PANI, polyaniline

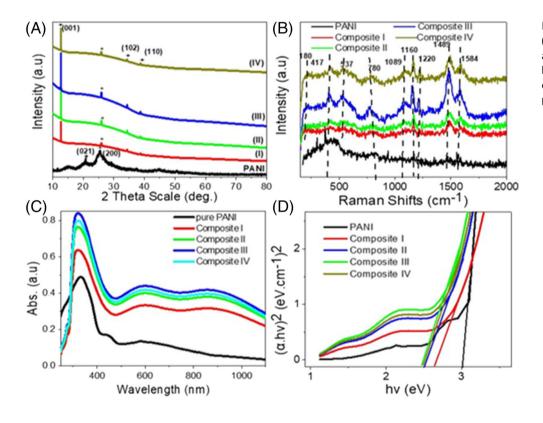


FIGURE 2 (A) XRD patterns, (B) Raman spectra, (C) optical absorbance, and (D) optical bandgap of PANI and PANI/Pbl₂ composites I, II, III, and IV. PANI, polyaniline; XRD, x-ray diffraction

878 nm appeared in the IR region. The increasing in the peak intensity indicates the enhancement in the optical properties related to high light response.³⁵ The peaks in the UV or Vis regions are related to the band-to-band electron transitions, while the peak in the IR region is related to the electron vibrations. The intensities of the peaks reached their optimum values in the composite III, in agreement with the XRD and Raman analyses.

The optical bandgap can be determined using the Kubelka–Munk equations (Equations 2–4)³⁶ using molar absorption coefficient (*K*) and scattering factor (*S*), as shown in Figure 2D. A bandgap of 3.0 eV was determined for PANI, this value well-matched with the recently-reported values.^{25,37} The band gap values of the PANI/Pbl₂ composites I, II, III, and IV were 2.63, 2.51, 2.46, and 2.49 eV, respectively. The enhancements in the bandgap values are related to the composite formation (PANI and Pbl₂) which accept a highly optical properties for enhancement its applications as a light detection device, in which the composite

III has the optimum bandgap (2.46 eV). This value favors the application of the composite III as an optoelectronic device, owing to its ability of light sensing through electron motion behavior.

$$F(R) = \frac{K}{S}$$
(2)

$$K = (1 - R)^2 \tag{3}$$

$$S = 2R$$
 (4)

The morphologies of the prepared PANI and PANI/Pbl₂ composites are assessed using SEM imaging (Figure 3). The SEM image of PANI in Figure 3A exhibits a homogeneous and porous polymer layer. The surface has a particle size of about 40 nm. In the SEM images of PANI/ Pbl₂ composites, Pbl₂ white spots covering the PANI network are

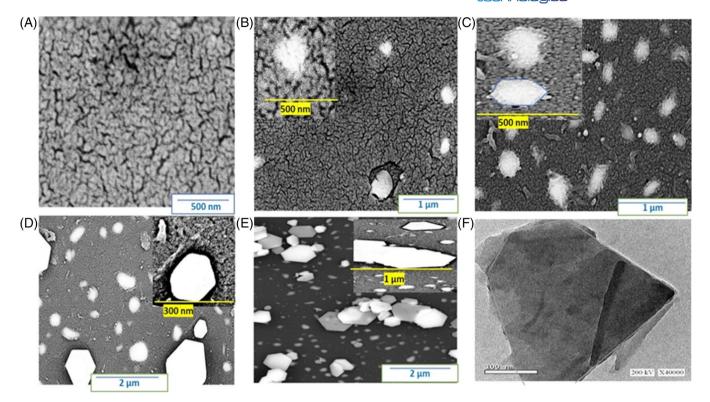


FIGURE 3 SEM images of (A) PANI, (B) composite I, (C) composite II, (D) composite III, and (E) composite IV. (F) TEM image of composite III. PANI, polyaniline; SEM, scanning electron microscopy

visible. These Pbl₂ white spots increase in number and size from composite I to III, Figure 3B–E, respectively. In addition to that, the Pbl₂ particles exhibit hexagonal shapes and form sheets over the surface of composites III and IV. The Pbl₂ average particle size increased with increasing of the Pb²⁺ concentration to reach 220, 270, 280 and 320 nm for composites I, II, III and IV, respectively.

TEM image of the composite III (Figure 3F) confirms that the Pbl_2 crystalline sheets grew throughout the PANI network with a particle size of about 280 nm.

The surface morphologies and cross-sections are confirmed with the software program (ImageJ), as shown in Figure 4. This software confirms the roughness behavior obtained from SEM analyses. From Figure 4A, PANI owns a rough uniform nonporous structure. The film thickness is about 580 nm. After composites' formation, the Pbl₂ particles appear like obelisks that penetrate the PANI network with cuboid and hexagonal structure. These obelisks shape increases in height and thickness from composite I to IV. The overall film thickness for the composites was about 1000 nm. The Pbl₂ has the optimum distribution in composite III, in accordance confirm with XRD, Raman, and optical analyses.

3.2 | The photodetector electrochemical study

3.2.1 | Effect of light intensity on the current density

The influence of light intensity on the produced current density (J_{ph}) of the optoelectronic photodetector, ATO/PANI/Pbl₂ (composite III),

was assessed and the results are presented in Figure 5A. Also, the recorded $J_{\rm ph}$ values at a bias of +1.0 V under light illumination are shown in Figure 5B. The results evidenced an increase in the $J_{\rm ph}$ values from 2.5 to 3.42 mA cm⁻² upon increasing of the light intensity from 25 to 100 mW cm⁻², respectively. This increase is related to the high sensitivity of the ATO/PANI/Pbl₂ photodetector to light illumination, which was able to detect small light intensity variation.³⁸ Under light illumination, the photodetector accepts more photons and liberates photoelectrons, which are collected on the surface, leading to enhanced current density, $J_{\rm ph}$. Moreover, $J_{\rm ph}$ values represent the light response due to the total electrons collected on the surface after their transfer from the valence band to the conduction band; the generated holes are collected on the other electrode side.^{29,39,40} The nonlinear relation indicates the generation of a Schottky barrier with the complex relation of holes and electrons.⁴¹

The high J_{ph} values of 3.42 mA cm⁻², recorded in a small potential range (-1 to +1 V), originates from the high surface area of the ATO/PANI/Pbl₂, owing to its high roughness and porous nature. These features increase the light sensing, especially with incorporating the Pbl₂ light spots that can detect even a small number of photons.

The reproducibility study of the ATO/PANI/Pbl₂ is displayed in Figure 5C under three separate runs. It is clear that the photodetector has great reproducibility with a standard deviation of 1.1%, reflecting the stability of the photodetector for light detection and sensing.

The dark current (J_d), due to charge accumulation under applied voltage, is presented in Figure 5D. The values recorded from -1 to +1 V are small in comparison with the J_{ph} values acquired under light irradiation.²²

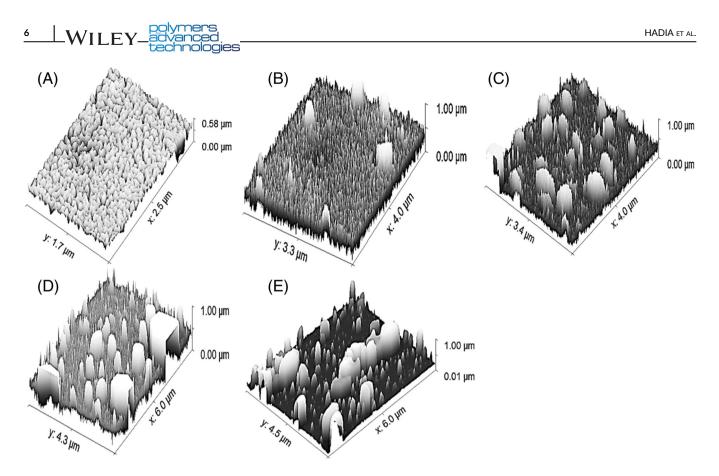


FIGURE 4 The surface roughness and cross-section of (A) polyaniline, (B) composite I, (C) composite II, (D) composite III, and (E) composite IV

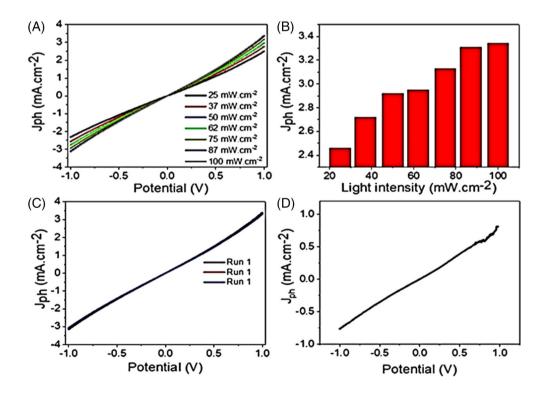
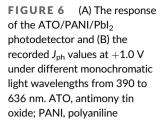


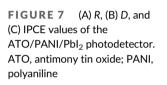
FIGURE 5 (A) The influence of light intensity, (B) current density recorded at +1.0 V versus light intensity, (C) reproducibility, and (D) dark current of the ATO/PANI/Pbl₂ photodetector at 25°C. ATO, antimony tin oxide; PANI, polyaniline

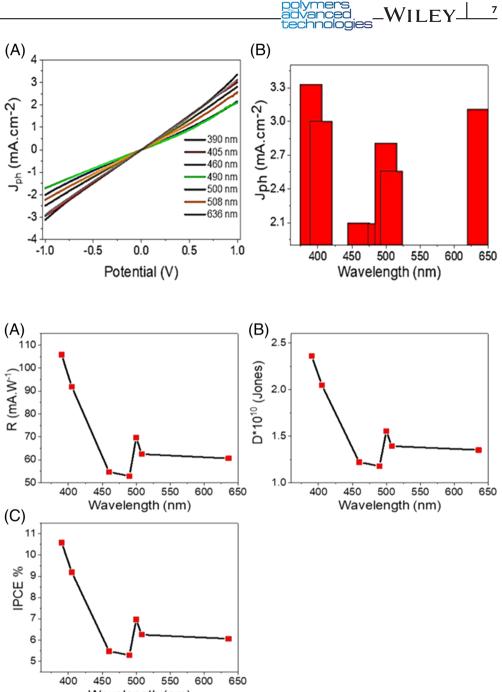
3.2.2 | Influence of light wavelength on the current density

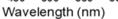
The effect of the monochromatic light (390–636 nm) on the ATO/ $PANI/PbI_2$ photodetector is summarized in Figure 6A. The

monochromatic light has a great influence on the photodetector response; the $J_{\rm ph}$ reached an optimum value of 3.33 mA cm⁻² at 390 nm, which decreased continuously to 2.09 mA cm⁻² at 490 nm. Then, there is an increase in the $J_{\rm ph}$ value again to 3.13 mA cm⁻² at 636 nm. The variation in the $J_{\rm ph}$ values matched well with the optical









absorption curve in Figure 2C. This behavior is clearly highlighted through the relation between the wavelengths and the recorded J_{ph} values at a constant potential of +1.0 V (Figure 6B). The J_{ph} values correspond to the light detection and sensing behavior.^{39,42,43}

The high J_{ph} value on the blue side is related to the high light frequency, while the high value on the red side is ascribed to the electron vibrations for the unsaturation properties in the IR region.^{42,44} These properties indicate the ability of the ATO/PANI/Pbl₂ photodetector to respond to light over a broad optical region including UV, Vis, and IR. So, the prepared photodetector is a unique device for light responding in these regions, with the great advantages of the very low cost that qualifies this photodetector for potential industrial applications.

3.2.3 | The efficiency of the optoelectronic device

The efficiency of the ATO/PANI/Pbl₂ photodetector depends on many parameters: IPCE, *R*, and *D* values. The *R* values depend on both J_{ph} and J_d under light irradiation and dark, respectively⁴⁵ along with the light intensity value (*P*), as shown in Equation (5).⁴⁶ This relation is represented in Figure 7B for different wavelengths. The results indicate that the prepared photodetector respond to light in a broad wavelength range from UV/Vis to near IR. The optimum photoresponsivity was 107 mA W⁻¹ at 390 nm.

The *D* value of the photodetector mainly depends on the *R* values, surface area (A), electron charge (e) and dark current, as shown in Equation (6) and Figure 7B. The device achieved an optimum

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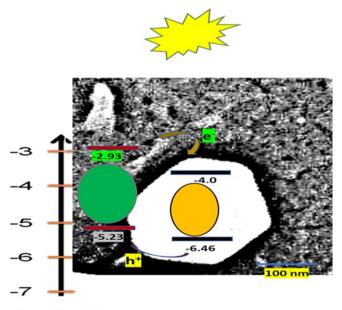
Structure [reference]	Wavelength (nm)	Bias (V)	R (mA W ⁻¹)
Polyaniline/MgZnO ⁴⁹	250	5	0.1
Diketopyrrolopyrrole ⁵⁰	390	0.1	36
Graphene/P3HT ⁵¹	325	1	N/A
N,N'-dioctyl-3,4,9,10-perylenedicarboximide ⁵²	480	1	20
TiO ₂ -PANI ⁵³	320	0	3
2,1,3-benzothiadiazole ¹⁹	734	0	N/A
PbI ₂ -5%Ag ¹²	532	6	N/A
Pbl ₂ -graphene ¹³	550	2	N/A
GO/Cu ₂ O ⁵⁴	300	2	0.5
CuO nanowires ⁹	390	5	-
ZnO/Cu ₂ O ¹⁰	350	2	4
ZnO-CuO ⁵⁵	405	1	3
CuO/Si nanowires ¹¹	405	0.2	3.8
TiN/TiO2 ³⁸	550	5	-
Se/TiO ₂ ⁵⁶	450	1	5
TiO ₂ /NiO ⁵⁷	350	0	0.4
Graphene/GaN ⁵⁸	365	7	3
ZnO /RGO ⁵⁹	350	5	1.3
Al-CdS ⁶⁰	532	5	0.1
CdS-ZnO ⁶¹	460	1	-
CdS ⁶²	840	-	3.8
ZnO/graphene/CdS ⁶³	365	0	2.7
TiN/TiO2 ³⁸	550	5	-
Se/TiO ₂ ⁵⁶	450	1	5
GO/Cu ₂ O ⁵⁴	300	2	0.5
ATO/PANI/Pbl ₂ (this work)	390	1	107

TABLE 1Comparison of theperformance of the prepared ATO/PANI/Pbl2 photodetector with previous works

Abbreviations: ATO, antimony tin oxide; PANI, polyaniline.

D value of 3.38 \times 10¹⁰ (Jones) at 390 nm and decreased to 1.16 \times 10¹⁰ Jones at 490 nm, followed by a small increase to reach 1.36 \times 10¹⁰ Jones at 636 nm. The large *D* values of the photodetector confirm its responsivity to different light wavelengths (UV, Vis, and near IR).

The IPCE⁴⁷ of the ATO/PANI/Pbl₂ photodetector was calculated using Equation (7),⁴⁸ and the obtained results are depicted in Figure 7C. The IPCE, corresponding to the electrons collected following the photon flux, reached an optimum value of 10.7% at 390 nm. This value decreased at 490 nm and increased again at 636 nm to 5.17% and 6%, respectively. Although there are variables in the IPCE values, the photodetector still features high values in all light regions. This property is related to the light absorption over a broad wavelength range. All these properties are related to the construction of the optoelectronic photodetector, in which the Pbl₂ has a great light absorption that can capture effectively the photons, and then transfer them to the PANI network to generate a photocurrent. So, the prepared ATO/PANI/Pbl₂ photodetector operates well under different light intensities and wavelengths, which qualifies it for potential industrial applications.



Energy level diagram

FIGURE 8 The mechanism of the ATO/PANI/Pbl₂ optoelectronic photodetector device. ATO, antimony tin oxide; PANI, polyaniline

$$R = \frac{J_{\rm ph} - J_{\rm d}}{P} \tag{5}$$

$$D = R \sqrt{A/2 e J_d} \tag{6}$$

$$EQE = R \frac{1240}{\lambda} 100 \tag{7}$$

The recorded IPCE, *R*, and *D* values of the prepared ATO/PANI/ Pbl₂ optoelectronic photodetector are compared with the previous results, as shown in Table 1. From this comparison, the prepared ATO/PANI/Pbl₂ optoelectronic device has a great photoresponsivity at a small bias voltage (1.0 V) in the visible region. This confirms the high sensitivity and detection of the light photons. These properties with the previous advantages qualify our photodetector for industrial applications.

3.3 | The mechanism of the light sensing

The plausible mechanism of light sensing by the ATO/PANI/Pbl₂ optoelectronic device is explained using the energy band theory (Figure 8). The porous network nature of PANI and the Pbl₂ nanomaterials with high light absorption behavior cause the creation of a bandgap. Upon light irradiation, electron-hole pairs are formed and the photoelectrons are collected at the surface.^{64,65} The bandgap of the PANI/PbI₂ composite is 2.46 eV, with a small depletion layer due to the transfer of electrons from the PANI to the Pbl₂ surface. This depletion layer appears as a Schottky barrier that forms the leakage in the behavior of the current-voltage curves. Although the presence of the Schottky barrier, there is a transfer of many hot electrons from the PANI surface to PbI_2 , which is reflected by the high J_{ph} value of 3.42 mA cm⁻² (Figure 5A). This behavior confirms that there is a continuous free electron flow with no carrier recombination.⁶⁶ After the electron transfer, the energy transfer due to the surface plasmonic resonance (localized SPR) appears through the electrons. These phenomena cause the accumulation of electrons on the Pbl₂ surface, resulting in high J_{ph} values. The hexagonal sheets of Pbl₂ (highly crystalline) increase the light capture through its small bandgap, and then increases the electron collections in its surface.⁶⁷

4 | CONCLUSIONS

A novel optoelectronic photodetector, ATO/PANI/Pbl₂ was prepared and assessed for light detection over a wide optical region ranging from UV, Vis, to near IR. The optoelectronic device responded to various light intensities from 25 to 100 mW.cm⁻² to produce enhanced current densities, J_{ph} , values of 2.5–3.42 mA cm⁻², respectively. Moreover, the photodetector has an excellent response to various wavelengths (390–636 nm), with a J_{ph} value of 3.33 mA cm⁻² recorded at 390 nm. This value decreased to 2.09 mA cm⁻² at 490 nm and increased again to 3.13 mA cm⁻² at 636 nm. Moreover, olymens advanced__WILEY_____%

the photodetector achieved optimum IPCE, *R*, and *D* values of 10.7%, 107 mA W⁻¹, and 3.38×10^{10} Jones, respectively. The ATO/PANI/Pbl₂ photodetector was qualified for its reproducibility, response to various light intensities, and operation under various light wavelengths (UV, Vis, and near IR). The obtained results combined with the low cost and easy preparation hold great promise for industrial application of the developed ATO/PANI/Pbl₂ photodetector.

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CONFLICT OF INTEREST

The authors declare no conflict of interest.

DATA AVAILABILITY STATEMENT

The data that support the findings of this study are available from the corresponding author upon reasonable request.

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